MN39260FH

4.5 mm (type-1/4) 810k-pixel CCD Area Image Sensor

Overview

The MN39260FH is a 4.5 mm (type-1/4) interline transfer CCD (IT-CCD) solid state image sensor device.

This device uses photodiodes in the optoelectric conversion section and CCDs for signal readout. The electronic shutter function has made an exposure time of 1/10000 seconds possible. Further, this device has the features of high sensitivity, low noise, broad dynamic range, and low smear.

This device has a total of $802\,579$ pixels (1 007 horizontal $\times\,797$ vertical) and provides stable and clear images with a resolution of 600 horizontal TV-lines and 420 vertical TV-lines.

| Part Number | Size | System | Color or B/W |
|-------------|-------------------|--------|--------------|
| MN39260FH | 4.5 mm (type-1/4) | PAL | Color |

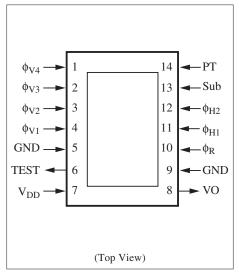
Features

- Effective pixel number 962 (horizontal) × 774 (vertical)
- High sensitivity
- Broad dynamic range
- Low smear
- Electronic shutter

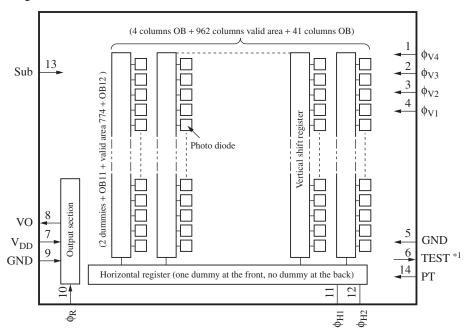
Applications

- Camcorders
- FA, OA cameras

■ Pin Assignments



■ Block Diagram



*1 : TEST pin must be left open, because the pin outputs CCD internal bias voltage.

■ Pin Descriptions

| Pin No. | Symbol | Description | Pin No. | Symbol | Description |
|---------|-----------------|---------------------------------------|---------|----------------|-----------------------------------|
| 1 | φ _{V4} | Vertical shift register clock pulse 4 | 8 | VO | Video output |
| 2 | φ _{V3} | Vertical shift register clock pulse 3 | 9 | GND | GND |
| 3 | φ _{V2} | Vertical shift register clock pulse 2 | 10 | φ _R | Reset pulse (RG) |
| 4 | φ _{V1} | Vertical shift register clock pulse 1 | 11 | ϕ_{H1} | Horizontal register clock pulse 1 |
| 5 | GND | GND | 12 | ϕ_{H2} | Horizontal register clock pulse 2 |
| 6 | TEST | TEST pin (OPEN) *1 | 13 | Sub | Substrate |
| 7 | V_{DD} | Power supply | 14 | PT | P-well for protection circuit |

Note) *1: TEST pin must be left open, because the pin outputs CCD internal bias voltage.

■ Device Parameter (H × V)

| Parameter | Value | Unit |
|-------------------------------|------------------------|-----------------|
| Pixel number *1 | 962 × 774 | pixel |
| Image sensing block dimension | 3.7037×2.7090 | mm ² |
| Pixel dimension | 3.85×3.50 | μm ² |

Note) *1: OB columns are not included.

■ Absolute Maximum Ratings and Operating Conditions

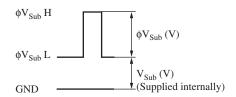
| Parameter | | Absolute maximum rating | | Operating condition | | | T |
|---------------------------|----------|-------------------------|-------------|---------------------|------|------|------|
| | | Lower limit | Upper limit | Min | Тур | Max | Unit |
| V_{DD} | | - 0.2 | 18 | 14.5 | 15.0 | 15.5 | V |
| V _{PT} *3, 4 | | -10.0 | 0.2 | -7.5 | -7.0 | -6.5 | V |
| GND | | (Referenc | e voltage) | _ | 0 | _ | V |
| $V_{\phi R}$ | High-Low | _ | 8 | 3.0 | 3.3 | 3.6 | V |
| | Bias | (Supplied internally) | | | | | V |
| $V_{\phi H1}$ | High | _ | 8 | 3.0 | 3.3 | 3.6 | V |
| | Low | - 0.2 | _ | - 0.2 | 0 | 0.2 | V |
| $V_{\phi H2}$ | High | _ | 8 | 3.0 | 3.3 | 3.6 | V |
| | Low | - 0.2 | _ | - 0.2 | 0 | 0.2 | V |
| V _{Sub} *2 | | | (S | upplied internally) | | | V |
| ϕV_{Sub}^{*1} | | - 0.2 | 35 | 21.0 | 22.0 | 23.0 | V |
| $V_{\phi V1}$ *3, 4 | High | _ | 18 | 14.5 | 15.0 | 15.5 | V |
| | Middle | _ | _ | - 0.05 | 0 | 0.05 | V |
| | Low | -9 | _ | -7.5 | -7.0 | -6.5 | V |
| $V_{\phi V2}^{\ *3,\ 4}$ | Middle | _ | 15 | - 0.05 | 0 | 0.05 | V |
| | Low | -9 | _ | -7.5 | -7.0 | -6.5 | V |
| V _{\phiV3} *3, 4 | High | _ | 18 | 14.5 | 15.0 | 15.5 | V |
| | Middle | _ | _ | - 0.05 | 0 | 0.05 | V |
| | Low | -9 | _ | -7.5 | -7.0 | -6.5 | V |
| $V_{\phi V4}^{\ *3,\ 4}$ | Middle | _ | 15 | - 0.05 | 0 | 0.05 | V |
| | Low | -9 | _ | -7.5 | -7.0 | -6.5 | V |
| Operating temperature | | -10 | 60 | _ | 25 | _ | °C |
| Storage temperature | | -30 | 80 | _ | _ | _ | °C |

■ Absolute Maximum Ratings and Operating Conditions (continued)

Note) 1. Standard photo detecting condition

Standard photo detecting condition stands for detecting image with a light source of color temperature of 2856K, luminance of 1050 cd/m², and using a color temperature conversion filter LB-40 (HOYA), infrared cut filter CAW-500S with thickness 2.5 mm for a light path and with F8 lens aperture. The quantity of the incidental light to a photo-detecting surface under the above condition is defined as the standard quantity of light.

2. $*1: V_{Sub}$ when using electronic shutter function



* \$\phi Sub pulse generates once every 1 V period.

- *2: V_{Sub} supplied internally is the voltage suppressing the blooming generation at $\times 500$ light quantity relative to the standard light quantity.
- *3: Relation between V_{PT} and $V_{\phi VL}$

Set V_{PT} under the following condition against VL of a vertical transfer clock waveform.

$$V_{PT} \le VL \ (V_{\phi V1L} \ to \ V_{\phi V4L})$$

*4: Absolute maximum ratings $-0.2 < V_{\phi V} - V_{PT} < 24.5 \text{ (V)}$

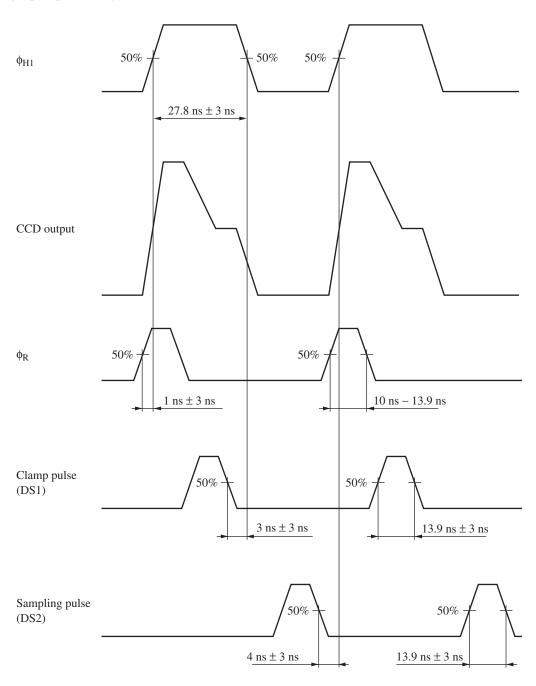
■ Optical Characteristics

| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|---------------------------|--------|-----------------------|-----|-----|------|------|
| Carrier saturation output | Sc | J chart | 500 | _ | _ | mV |
| Sensitivity | So | J chart F1.4, 1/32 ND | 80 | 110 | _ | mV |
| Vertical smear | Sm | 1/10 V chart, F1.4 | _ | _ | 0.01 | % |

Note) The above-mentioned characteristics are the values on driving the device for the imaging stabilizer mode (1/60 seconds accumulation).

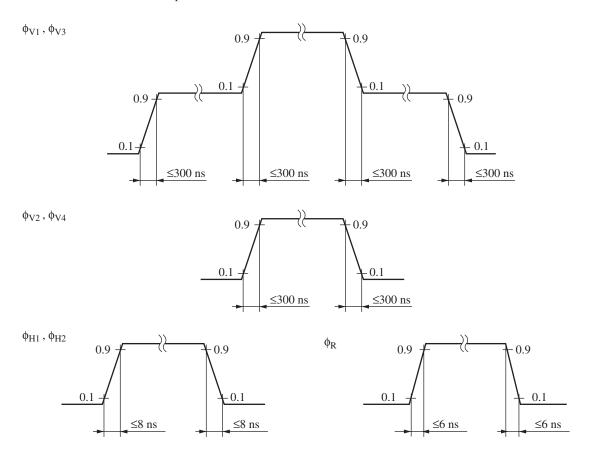
■ Timing Diagram

• High speed pulse timing

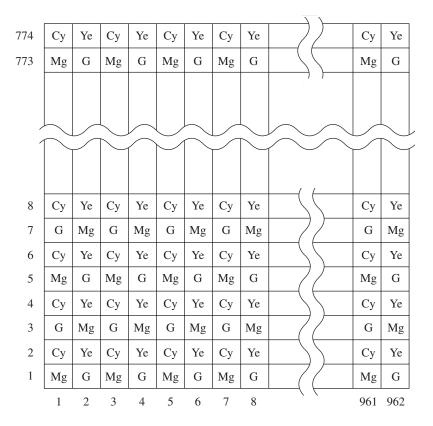


■ Timing Diagram (continued)

• Rise time and fall time of each pulse

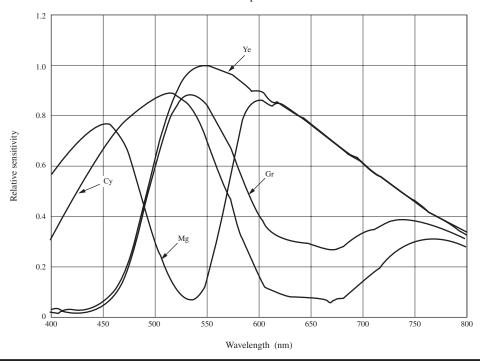


■ Color Filter Arrays on CCD



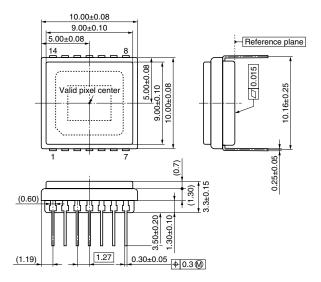
■ Graph of Characteristics

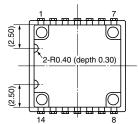
CCD color filter spectral characteristics



■ Package Dimensions (unit: mm)

• WDIP014-P-0400H





- 1. The center of the package is equal to the center of the effective pixel area.
- 2. The rotation angle of the effective pixel area: up to ± 1.0 degree
- 3. The distance from the bottom face of the package to the surface of the effective pixel area: 1.41 mm \pm 0.1 mm
- 4. The tilt of the effective pixel area for the bottom face of the package: up to 25 μm
- 5. Thickness of seal glass is 0.7 mm \pm 0.1 mm, and the refractive index is 1.50.
- 6. Package weight: 0.55 g (typ.)

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